



SLLS944-NOVEMBER 2008

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3.3-V CAN TRANSCEIVER

FEATURES

- Bus-Pin Fault Protection Exceeds ±36 V
- **Bus-Pin ESD Protection Exceeds 16-kV HBM**
- **Compatible With ISO 11898** .
- Signaling Rates⁽¹⁾ up to 1 Mbps
- Extended -7-V to 12-V Common-Mode Range
- High-Input Impedance Allows for 120 Nodes
- LVTTL I/Os Are 5-V Tolerant
- Adjustable Driver Transition Times for Improved Signal Quality
- **Unpowered Node Does Not Disturb the Bus**
- Low-Current Standby Mode . . . 200-µA Typical
- **Thermal Shutdown Protection**
- Power-Up/Down Glitch-Free Bus Inputs and Outputs
 - High Input Impedance With Low V_{cc}
 - Monolithic Output During Power Cycling
- Loopback for Diagnostic Functions Available
- **DeviceNet Vendor ID #806**
- (1)The signaling rate of a line is the number of voltage transitions that are made per second expressed in the units bps (bits per second).

SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

- **Controlled Baseline**
- **One Assembly/Test Site**
- **One Fabrication Site**
- Available in Military (-55°C/125°C) Temperature Range⁽¹⁾
- Extended Product Life Cycle
- **Extended Product-Change Notification** .
- **Product Traceability**
- (1) Additional temperature ranges available contact factory

APPLICATIONS

- CAN Data Bus
- Industrial Automation
 - DeviceNet[™] Data Buses
 - Smart Distributed Systems (SDS™)
- SAE J1939 Standard Data Bus Interface
- NMEA 2000 Standard Data Bus Interface
- ISO 11783 Standard Data Bus Interface

DESCRIPTION

The SN65HVD233 is used in applications employing controller area network (CAN) the serial communication physical layer in accordance with the ISO 11898 standard. As a CAN transceiver, it provides transmit and receive capability between the differential CAN bus and a CAN controller, with signaling rates up to 1 Mbps.

Designed for operation in especially harsh environments, the device features cross-wire, overvoltage and loss of ground protection to ±36 V, with overtemperature protection and common-mode transient protection of ±100 V. This device operates over a -7-V to 12-V common-mode range with a maximum of 60 nodes on a bus.

FUNCTIONAL BLOCK DIAGRAM





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This device has limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

DESCRIPTION (CONTINUED)

If the common-mode range is restricted to the ISO-11898 Standard range of -2 V to 7 V, up to 120 nodes may be connected on a bus. This transceiver interfaces the single-ended CAN controller with the differential CAN bus found in industrial, building automation, and automotive applications.

The R_S (pin 8) of the SN65HVD233 provides for three modes of operation: high-speed, slope control, or low-power standby mode. The high-speed mode of operation is selected by connecting R_S directly to ground, allowing the driver output transistors to switch on and off as fast as possible with no limitation on the rise and fall slope. The rise and fall slope can be adjusted by connecting a resistor to ground at R_S, since the slope is proportional to the pin's output current. Slope control is implemented with a resistor value of 10 k Ω to achieve a slew rate of \approx 15 V/µs and a value of 100 k Ω to achieve \approx 2.0 V/µs slew rate. For more information about slope control, refer to the application information section.

The SN65HVD233 enters a low-current standby mode during which the driver is switched off and the receiver remains active if a high logic level is applied to R_S . The local protocol controller reverses this low-current standby mode when it needs to transmit to the bus.

A logic high on the loopback LBK (pin 5) of the SN65HVD233 places the bus output and bus input in a high-impedance state. The remaining circuit remains active and available for driver to receiver loopback, self-diagnostic node functions without disturbing the bus.

AVAILABLE OPTIONS

PART NUMBER	LOW POWER MODE	SLOPE CONTROL	DIAGNOSTIC LOOPBACK	AUTOBAUD LOOPBACK
SN65HVD233	200-µA standby mode	Adjustable	Yes	No
	ORDERING INFORMAT	ION ⁽¹⁾		

T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–55°C to 125°C	SOIC – D	Reel of 2500	SN65HVD233MDREP	H233EP

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com.

(2) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

POWER DISSIPATION RATINGS

PACKAGE	CIRCUIT BOARD	T _A ≤ 25°C POWER RATING	DERATING FACTOR ⁽¹⁾ ABOVE T _A = 25°C	T _A = 85°C POWER RATING	T _A = 125°C POWER RATING
D	Low-K	596.6 mW	5.7 mW/°C	255.7 mW	28.4 mW
D	High-K	1076.9 mW	10.3 mW/°C	461.5 mW	51.3 mW

(1) This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾ ⁽²⁾

over operating free-air temperature range (unless otherwise noted)

				VALUE	UNIT
V _{CC}	Supply voltage range			–0.3 to 7	V
	Voltage range at any bu	s terminal (CANH or CANL)		-36 to 36	V
	Voltage input range, trai	nsient pulse, CANH and CANL	., through 100 Ω (see Figure 7)	-100 to 100	V
VI	Input voltage range, (D,	R, R _S , LBK)		-0.5 to 7	V
I _O	Receiver output current	r output current		-10 to 10	mA
	Electrostatic discharge	Human Body Model ⁽³⁾	CANH, CANL and GND	16	kV
	Electrostatio discharge	Human Body Model ⁽³⁾	All pins	3	kV
	Electrostatic discharge	Charged-Device Mode ⁽⁴⁾	All pins	1	kV
	Continuous total power	dissipation		See Dissipation Rating Table	
TJ	Operating junction temp	erature		150	°C

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

(3) Tested in accordance with JEDEC Standard 22, Test Method A114-A.

(4) Tested in accordance with JEDEC Standard 22, Test Method C101.

RECOMMENDED OPERATING CONDITIONS

			MIN	TYP MAX	UNIT
V _{CC}	Supply voltage		3	3.6	
	Voltage at any bus terminal (separate	y or common mode)	-7	12	
V _{IH}	High-level input voltage	D, LBK	2	5.5	V
VIL	Low-level input voltage	D, LBK	0	0.8	
V_{ID}	Differential input voltage		-6	6	
	sistance from R _S to ground		0	100	kΩ
V _{I(Rs)}	Input Voltage at R _S for standby		0.75 V _{CC}	5.5	V
	Lich lovel output ourrent	Driver	-50		
ЮН		Receiver	-10		ШA
		Driver		50	~
OL	Low-level output current	Receiver		10	ШA
TJ	Operating junction temperature			150	°C
T _A	Operating free-air temperature ⁽¹⁾		-55	125	°C

(1) Maximum free-air temperature operation is allowed as long as the device maximum junction temperature is not exceeded.

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DRIVER ELECTRICAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

	PARAM	ETER		TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
	Bus output voltage		CANH		2.45		V_{CC}	
V _{O(D)}	(Dominant)		CANL	$D = 0.0$, $R_S = 0.0$, See Figure 1 and Figure 2	0.5		1.25	V
V	Bus output voltage		CANH			2.3		V
vo	(Recessive)		CANL	$-D = 3$ V, $R_S = 0$ V, See Figure 1 and Figure 2		2.3		v
V	Differential output y	altara (Dar	min ant)	$D = 0 V$, $R_S = 0 V$, See Figure 1 and Figure 2	1.5	2	3	V
VOD(D)	Differential output v	ollage (Dor	ninant)	$D = 0 V$, $R_S = 0 V$, See Figure 2 and Figure 3	1.2	2	3	v
N/	Differential entrution	altara (Da		$D = 3 V, R_S = 0 V, See Figure 1 and Figure 2$	-120		12	mV
VOD	Differential output v	oltage (Red	cessive)	$D = 3 V, R_S = 0 V, No load$	-0.5		0.05	V
V _{OC(pp)}	Peak-to-peak comm	non-mode c	output voltage	See Figure 9		1		V
I _{IH}	High-level input cur	rent	D,LBK	D = 2 V	-30		30	μΑ
IIL	Low-level input curr	ent	D, LBK	D = 0.8 V	-30		30	μΑ
				V _{CANH} = -7 V, CANL Open, See Figure 12	-250			
	Chart since it sectored			V _{CANH} = 12 V, CANL Open, See Figure 12			1	
IOS	Short-circuit output	current		V _{CANL} = -7 V, CANH Open, See Figure 12	-1			ША
				V _{CANL} = 12 V, CANH Open, See Figure 12			250	
Co	Output capacitance			See receiver input capacitance				
I _{IRs(s)}	R _S input current for	standby		$R_{S} = 0.75 V_{CC}$	-10			μA
		Standby		$R_{S} = V_{CC}, D = V_{CC}, LBK = 0 V$		200	600	μA
I _{CC}	cc Supply current Dominant		t				6	~ ^
		Recessive	e	$D = V_{CC}$, No load, LBK = 0 V, R _S = 0 V			6	ШA

(1) All typical values are at 25° C and with a 3.3 V supply.



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DRIVER SWITCHING CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
	-	$R_S = 0 V$, See Figure 4		35	95	
t _{PLH}	Propagation delay time, low-to-high-level output	R_S with 10 k Ω to ground, See Figure 4		70	125	ns
		R_S with 100 k Ω to ground, See Figure 4		500	870	
		R _S = 0 V, See Figure 4		70	120	
t _{PHL}	Propagation delay time,	R_S with 10 k Ω to ground, See Figure 4		130	180	ns
		R_S with 100 k Ω to ground, SeeFigure 4		870	1200	
		R _S = 0 V, See Figure 4		35		
t _{sk(p)}	Pulse skew (t _{PHL} – t _{PLH})	R_S with 10 k Ω to ground, See Figure 4		60		ns
		R_S with 100 k Ω to ground, SeeFigure 4		370		
t _r	Differential output signal rise time		20		70	~~
t _f	Differential output signal fall time	$R_{S} = 0$ V, See Figure 4	20		70	ns
t _r	Differential output signal rise time	D with 40 k0 to ground Cos Figure 4	30		135	
t _f	Differential output signal fall time	R _S with 10 kΩ to ground, See Figure 4	30		135	ns
t _r	Differential output signal rise time	D with 400 k0 to secure 4 Cap Figure 4	300		1400	
t _f	Differential output signal fall time	R _S with 100 kt2 to ground, See Figure 4	300		1400	ns
t _{en(s)}	Enable time from standby to dominant	See Figure 8		0.6	1.5	μs

(1) All typical values are at 25°C and with a 3.3 V supply. Timing parameters are characterized but not production tested.

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RECEIVER ELECTRICAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

	PARAME	TER	TEST CO	ONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V_{IT+}	Positive-going inp	ut threshold voltage ⁽²⁾				750	900	
V _{IT-}	Negative-going in voltage ⁽²⁾	put threshold	LBK = 0 V, See Table 1		500	650		mV
V _{hys}	Hysteresis voltage	e (V _{IT+} – V _{IT–})				100		
V _{OH}	High-level output	voltage	$I_{O} = -4$ mA, See Figure 6	$_{\rm O}$ = -4 mA, See Figure 6				V
V _{OL}	Low-level output v	/oltage	I _O = 4 mA, See Figure 6	_O = 4 mA, See Figure 6			0.4	v
			CANH or CANL = 12 V		150		500	
	Due in a terment		CANH or CANL = 12 V, $V_{CC} = 0 V$	Other bus pin = $0 V$,	200		600	
II.	II Bus input current		CANH or CANL = -7 V	$R_{\rm S} = 0 V$	-610		-150	μΑ
			CANH or CANL = -7 V , V _{CC} = 0 V		-450		-130	
CI	Input capacitance	(CANH or CANL)	Pin-to-ground, V _I = 0.4 sin (4E6 π t) + 0.5V, D = 3 V, LBK = 0 V			40		<u>م</u> ۲
C _{ID}	Differential input of	capacitance	Pin-to-pin, $V_1 = 0.4 \sin (4E6\pi t) + 0.5V$, $D = 3 V$, LBK = 0 V			20		рн
R _{ID}	Differential input r	esistance			40		100	1.0
R _{IN}	Input resistance (CANH or CANL)	D = 3 V, LBK = 0 V	= 3 V, LBK = 0 V			50	KΩ
		Sleep	$D = V_{CC}, R_S = 0 V \text{ or } V_{CC}$			0.05	2	۵
	Supply ourropt	Standby	$R_S = V_{CC}, D = V_{CC}, LBK =$	0 V		200	600	μΑ
'CC	Supply current	Dominant	$D = 0 V$, No load, $R_S = 0 V$	′, LBK = 0 V			6	~ ^
		Recessive	$D = V_{CC}$, No load, $R_S = 0$ V	/, LBK = 0 V			6	mA

All typical values are at 25°C and with a 3.3 V supply. Characterized but not production tested. (1)

(2)



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RECEIVER SWITCHING CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN TYP ⁽¹⁾	MAX	UNIT
t _{PLH}	Propagation delay time, low-to-high-level output		35	60	
t _{PHL}	Propagation delay time, high-to-low-level output		35	60	
t _{sk(p)}	Pulse skew (t _{PHL} – t _{PLH})	See Figure 6	7		ns
t _r	Output signal rise time		2	6.5	
t _f	Output signal fall time		2	6.5	

(1) All typical values are at 25°C and with a 3.3 V supply. Timing parameters are characterized but not production tested.

DEVICE SWITCHING CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
t _(LBK)	Loopback delay, driver input to receiver output	HVD233	See Figure 11		7.5	13	ns
	T (1)		R _S = 0 V, See Figure 10		70	135	
t _(loop1)	Total loop delay, driver input to receiver output t(loop1) recessive to dominant	eceiver output,	R_S with 10 k Ω to ground, See Figure 10		105	190	ns
			R_S with 100 $k\Omega$ to ground, See Figure 10		535	1000	
			R _S = 0 V, See Figure 10		70	135	
t(loop2) Total loop delay, driver input to receiver outp		eceiver output,	R_S with 10 $k\Omega$ to ground, See Figure 10		105	190	ns
			R_S with 100 k Ω to ground, See Figure 10		535	1100	

(1) All typical values are at 25°C and with a 3.3 V supply. Timing parameters are characterized but not production tested.



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PARAMETER MEASUREMENT INFORMATION







Figure 2. Bus Logic State Voltage Definitions



Figure 3. Driver V_{OD}



- A. The input pulse is supplied by a generator having the following characteristics: Pulse repetition rate (PRR) \leq 125 kHz, 50% duty cycle, t_r \leq 6 ns, t_f \leq 6 ns, Z₀ = 50 Ω .
- B. C_L includes fixture and instrumentation capacitance.

Figure 4. Driver Test Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION (continued)



Figure 5. Receiver Voltage and Current Definitions



- A. The input pulse is supplied by a generator having the following characteristics: Pulse repetition rate (PRR) \leq 125 kHz, 50% duty cycle, t_r \leq 6 ns, t_f \leq 6 ns, Z_O = 50 Ω .
- B. C_L includes fixture and instrumentation capacitance.

Figure 6. Receiver Test Circuit and Voltage Waveforms

INF	TUT	OU.	TPUT	MEASURED			
V _{CANH}	V _{CANL}		R	V _{ID}			
–6.1 V	-7 V	L		900 mV			
12 V	11.1 V	L	N/	900 mV			
-1 V	-7 V	L	VOL	6 V			
12 V	6 V	L		6 V			
–6.5 V	-7 V	н		500 mV			
12 V	11.5 V	Н		500 mV			
-7 V	-1 V	Н	V _{OH}	6 V			
6 V	12 V	н		6 V			
Open	Open	Н		Х			

Table 1. Differential Input Voltage Threshold Test



NOTE: This test is conducted to test survivability only. Data stability at the R output is not specified.

Figure 7. Test Circuit, Transient Over Voltage Test







NOTE: All V₁ input pulses are supplied by a generator having the following characteristics: t_r or t_f ≤ 6 ns, pulse repetition rate (PRR) = 125 kHz, 50% duty cycle.





NOTE[:] All V_I input pulses are supplied by a generator having the following characteristics: t_r or t_f \leq 6 ns, pulse repetition rate (PRR) = 125 kHz, 50% duty cycle.





NOTE: All V₁ input pulses are supplied by a generator having the following characteristics: $t_f \text{ or } t_f \leq 6 \text{ ns}$, pulse repetition rate (PRR) = 125 kHz, 50% duty cycle.

Figure 10. t_(loop) Test Circuit and Voltage Waveforms

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NOTE: All V_I input pulses are supplied by agenerator having the following characteristics: t_r or $t_f \le 6$ ns, pulse repetition rate (PRR) = 125 kHz, 50% duty cycle.





Figure 12. I_{OS} Test Circuit and Waveforms







The R Output State Does Not Change During Application of the Input Waveform.



NOTE: All input pulses are supplied by a generator with f \leq 1.5 MHz.

Figure 13. Common-Mode Voltage Rejection

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DEVICE INFORMATION



EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS





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Table 2. Thermal Characteristics

	PARAMETERS	TEST CONDITIONS	VALUE	UNIT
0	lunction to ambient thermal registeres (1)	Low-K ⁽²⁾ board, no air flow	185	°C/W
OJA		High-K ⁽³⁾ board, no air flow	101	
θ_{JB}	Junction-to-board thermal resistance	High-K ⁽³⁾ board, no air flow	82.8	°C/W
θ_{JC}	Junction-to-case thermal resistance		26.5	°C/W
P _(AVG)	Average power dissipation	R_L = 60 Ω, R_S at 0 V, input to D a 1-MHz 50% duty cycle square wave V _{CC} at 3.3 V, T_A = 25°C	36.4	mW
T _(SD)	Thermal shutdown junction temperature		170	°C

(1) See TI literature number SZZA003 for an explanation of this parameter.

(2) JESD51-3 low effective thermal conductivity test board for leaded surface mount packages.

(3) JESD51-7 high effective thermal conductivity test board for leaded surface mount packages.

FUNCTION TABLES

DRIVER ⁽¹⁾									
	INPUTS		OUTPUTS						
D	LBK/AB	R _s	CANH	BUS STATE					
Х	Х	> 0.75 V _{CC}	Z	Z	Recessive				
L	L or open	< 0.22 V	Н	L	Dominant				
H or open	Х	≤ 0.33 V _{CC}	Z	Z	Recessive				
X	Н	≤ 0.33 V _{CC}	Z	Z	Recessive				

(1) H = high level; L = low level; Z = high impedance; X = irrelevant; ? = indeterminate

RECEIVER ⁽¹⁾									
	OUTPUT								
BUS STATE	$V_{ID} = V_{(CANH)} - V_{(CANL)}$	LBK	D	R					
Dominant	$V_{ID} \ge 0.9 V$	L or open	Х	L					
Recessive	$V_{ID} \le 0.5 \text{ V or open}$	L or open	H or open	н					
?	0.5 V < V _{ID} <0.9 V	L or open	H or open	?					
Х	X X		L	L					
Х	Х		Н	Н					

(1) H = high level; L = low level; Z = high impedance; X = irrelevant; ? = indeterminate

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TYPICAL CHARACTERISTICS RECESSIVE-TO-DOMINANT LOOP TIME DOMINANT-TO-RECESSIVE LOOP TIME vs FREE-AIR TEMPERATURE vs FREE-AIR TEMPERATURE 90 t^{t} (LOOPL2 \mathfrak{I} Dominant-T o-Recessive Loop Time - ns 95 Rs, LBK = 0 V Rs, LBK = 0 V 85 90 $V_{CC} = 3 V$ 80 85 $V_{CC} = 3.3 V$ $V_{CC} = 3.6 V$ $V_{CC} = 3.6 V$ 75 80 $V_{CC} = 3.3 V$ 70 75 65 70 $V_{CC} = 3 V$ 60 65 -40 5 45 80 125 45 -40 5 80 125 T_A - Free-Air Temperature - °C T_A - Free-Air Temperature - °C Figure 14. Figure 15. SUPPLY CURRENT DRIVER LOW-LEVEL OUTPUT CURRENT vs FREQUENCY vs LOW-LEVEL OUTPUT VOLTAGE 20 160 $\label{eq:V_CC} \begin{array}{l} \mathsf{V}_{\text{CC}} = 3.3 \ \text{V}, \\ \mathsf{Rs}, \ \mathsf{LBK} = 0 \ \text{V}, \end{array}$ $V_{CC} = 3.3 V,$ Rs, LBK = 0 V, 140 T_A = 25°C T_A = 25°C, 19 OL - Driver Output Current - mA **60-** Ω Load Icc - Suppl y Current - mA 120 100 18 80 17 60 40 16 20 15└─ 200 0 300 500 700 1000 2 3 0 1 4 VOL - Lo w-Level Output Voltage - V f - Frequenc y - kbps Figure 16. Figure 17.



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TYPICAL CHARACTERISTICS (continued)



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TYPICAL CHARACTERISTICS (continued)

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APPLICATION INFORMATION

DIAGNOSTIC LOOPBACK (SN65HVD233)

The loopback function of the SN65HVD233 is enabled with a high-level input to LBK. This forces the driver into a recessive state and redirects the data (D) input at pin 1 to the received-data output (R) at pin 4. This allows the host controller to input and read back a bit sequence to perform diagnostic routines without disturbing the CAN bus. A typical CAN bus application is displayed in Figure 25.

If the LBK pin is not used it may be tied to ground (GND). However, it is pulled low internally (defaults to a low-level input) and may be left open if not in use.



Figure 25. Typical HVD233 Application

ISO 11898 COMPLIANCE OF SN65HVD230 FAMILY OF 3.3-V CAN TRANSCEIVERS

Introduction

Many users value the low power consumption of operating their CAN transceivers from a 3.3 V supply. However, some are concerned about the interoperability with 5-V supplied transceivers on the same bus. This report analyzes this situation to address those concerns.

Differential Signal

CAN is a differential bus where complementary signals are sent over two wires and the voltage difference between the two wires defines the logical state of the bus. The differential CAN receiver monitors this voltage difference and outputs the bus state with a single-ended output signal.



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Figure 26. Typical SN65HVD230 Differential Output Voltage Waveform

The CAN driver creates the difference voltage between CANH and CANL in the dominant state. The dominant differential output of the SN65HVD230 is greater than 1.5 V and less than 3 V across a 60-ohm load. The minimum required by ISO 11898 is 1.5 V and maximum is 3 V. These are the same limiting values for 5-V supplied CAN transceivers. The bus termination resistors drive the recessive bus state and not the CAN driver.

A CAN receiver is required to output a recessive state with less than 500 mV and a dominant state with more than 900 mV difference voltage on its bus inputs. The CAN receiver must do this with common-mode input voltages from -2 V to 7 V. The SN65HVD230 family receivers meet these same input specifications as 5-V supplied receivers.

Common-Mode Signal

A common-mode signal is an average voltage of the two signal wires that the differential receiver rejects. The common-mode signal comes from the CAN driver, ground noise, and coupled bus noise. Obviously, the supply voltage of the CAN transceiver has nothing to do with noise. The SN65HVD230 family driver lowers the common-mode output in a dominant bit by a couple hundred millivolts from that of most 5-V drivers. While this does not fully comply with ISO 11898, this small variation in the driver common-mode output is rejected by differential receivers and does not effect data, signal noise margins or error rates.

Interoperability of 3.3-V CAN in 5-V CAN Systems

The 3.3-V supplied SN65HVD23x family of CAN transceivers are electrically interchangeable with 5-V CAN transceivers. The differential output is the same. The recessive common-mode output is the same. The dominant common-mode output voltage is a couple hundred millivolts lower than 5-V supplied drivers, while the receivers exhibit identical specifications as 5-V devices.

Electrical interoperability does not assure interchangeability however. Most implementers of CAN buses recognize that ISO 11898 does not sufficiently specify the electrical layer and that strict standard compliance alone does not ensure interchangeability. This comes only with thorough equipment testing.

BUS CABLE

The ISO-11898 Standard specifies a maximum bus length of 40 m and maximum stub length of 0.3 m with a maximum of 30 nodes. However, with careful design, users can have longer cables, longer stub lengths, and many more nodes to a bus. A large number of nodes requires a transceiver with high input impedance such as the SN65HVD233.

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The standard specifies the interconnect to be a single twisted-pair cable (shielded or unshielded) with $120-\Omega$ characteristic impedance (Z₀). Resistors equal to the characteristic impedance of the line terminate both ends of the cable to prevent signal reflections. Unterminated drop-lines (stubs) connecting nodes to the bus should be kept as short as possible to minimize signal reflections.

SLOPE CONTROL

The rise and fall slope of the SN65HVD233 driver output can be adjusted by connecting a resistor from R_s (pin 8) to ground (GND), or to a low-level input voltage as shown in Figure 27.

The slope of the driver output signal is proportional to the pin's output current. This slope control is implemented with an external resistor value of 10 k Ω to achieve a \approx 15 V/µs slew rate, and up to 100 k Ω to achieve a \approx 2.0 V/µs slew rate as displayed in Figure 28. Typical driver output waveforms with slope control are displayed in Figure 29.



Figure 27. Slope Control/Standby Connection to a DSP



Figure 28. SN65HVD233 Driver Output Signal Slope vs Slope Control Resistance Value





Figure 29. Typical SN65HVD233 250-kbps Output Pulse Waveforms With Slope Control

STANDBY

If a high-level input (> 0.75 V_{CC}) is applied to Rs (pin 8), the circuit enters a low-current, *listen only* standby mode during which the driver is switched off and the receiver remains active. The local controller can reverse this low-power standby mode when the rising edge of a dominant state (bus differential voltage >900 mV typical) occurs on the bus.



10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN65HVD233MDREP	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	H233EP	Samples
V62/09611-01XE	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	H233EP	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

OTHER QUALIFIED VERSIONS OF SN65HVD233-EP :

• Catalog: SN65HVD233

• Automotive: SN65HVD233-Q1

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects



TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



All dimensions are nominal												
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65HVD233MDREP	SOIC	D	8	2500	330.0	12.5	6.4	5.2	2.1	8.0	12.0	Q1



PACKAGE MATERIALS INFORMATION

25-Sep-2024



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65HVD233MDREP	SOIC	D	8	2500	353.0	353.0	32.0

D0008A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



D0008A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0008A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



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